

RoHS Compliant Product
A suffix of "-C" specifies halogen & lead-free

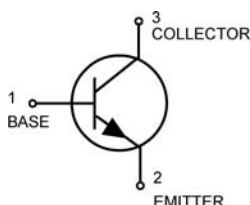
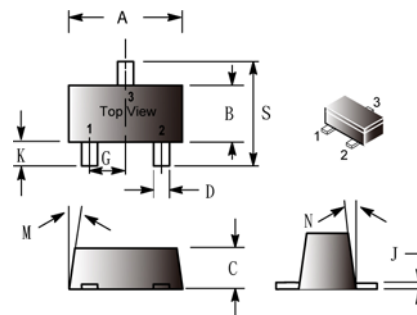
SOT-523

FEATURES

- Simplifies Circuit Design.
- We Declare that the material of product compliance with RoHS requirements.

ORDERING INFORMATION

Device	Marking	Shipping
MMBT3904T	MA	3000/Tape&Reel



REF.	Millimeter		REF.	Millimeter	
	Min.	Max.		Min.	Max.
A	1.50	1.70	K	0.30	0.50
B	0.75	0.95	M	---	10°
C	0.60	0.80	N	---	10°
D	0.23	0.33	S	1.50	1.70
G	0.50BSC				
J	0.10	0.20			

MAXIMUM RATINGS (at $T_a = 25^\circ\text{C}$ unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT
Collector - Emitter Voltage	V_{CEO}	40	Vdc
Collector - Base Voltage	V_{CBO}	60	Vdc
Emitter - Base Voltage	V_{EBO}	6.0	Vdc
Collector Current - Continuous	I_C	200	mAdc
Total Device Dissipation FR-4 Board ⁽¹⁾ $T_A=25^\circ\text{C}$, Derate above 25°C	P_D	200	mW
		1.6	mW/ $^\circ\text{C}$
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	600	$^\circ\text{C} / \text{W}$
Total Device Dissipation FR-4 Board ⁽²⁾ $T_A=25^\circ\text{C}$, Derate above 25°C	P_D	300	mW
		2.4	mW/ $^\circ\text{C}$
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	400	$^\circ\text{C} / \text{W}$
Junction & Storage Temperature	T_J, T_{STG}	-55 ~ 150	$^\circ\text{C}$

1. FR-4 Minimum Pad.
2. FR-4 1.0 X 1.0 Inch Pad.
3. Pulse Test : Pulse Width $\leq 300 \mu\text{s}$, Duty Cycle $\leq 2.0\%$.

DEVICE MARKING

MMBT3904T1G=AM

ELECTRICAL CHARACTERISTICS (at $T_a = 25^\circ\text{C}$ unless otherwise specified)

CHARACTERISTIC	SYMBOL	MIN.	MAX.	UNIT	TEST CONDITIONS
Off Characteristics					
Collector-Emitter Breakdown Voltage ⁽³⁾	$V_{(BR)CEO}$	40	-	Vdc	$I_C = 1.0 \text{ mAdc}$
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	60	-	Vdc	$I_C = 10 \mu\text{Adc}$
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	6.0	-	Vdc	$I_E = 10 \mu\text{Adc}$
Collector Cut-Off Current	I_{BL}	-	50	nAdc	$V_{CE} = 30 \text{ Vdc}, V_{EB} = 3.0 \text{ Vdc}$
Emitter Cut-Off Current	I_{CEX}	-	50	nAdc	$V_{CE} = 30 \text{ Vdc}, V_{BE} = 3.0 \text{ Vdc}$
On Characteristics⁽³⁾					
DC Current Gain ⁽¹⁾	h_{FE}	40	-	-	$I_C = 0.1 \text{ mAdc}, V_{CE} = 1.0 \text{ Vdc}$
		70	-		$I_C = 1.0 \text{ mAdc}, V_{CE} = 1.0 \text{ Vdc}$
		100	300		$I_C = 10 \text{ mAdc}, V_{CE} = 1.0 \text{ Vdc}$
		60	-		$I_C = 50 \text{ mAdc}, V_{CE} = 1.0 \text{ Vdc}$
		30	-		$I_C = 100 \text{ mAdc}, V_{CE} = 1.0 \text{ Vdc}$
Collector-Emitter Saturation Voltage ⁽³⁾	$V_{CE(sat)}$	-	0.2	Vdc	$I_C = 10 \text{ mAdc}, I_B = 1.0 \text{ mAdc}$
		-	0.3		$I_C = 50 \text{ mAdc}, I_B = 5.0 \text{ mAdc}$
Base-Emitter Saturation Voltage ⁽³⁾	$V_{BE(sat)}$	0.65	0.85	Vdc	$I_C = 10 \text{ mAdc}, I_B = 1.0 \text{ mAdc}$
		-	0.95		$I_C = 50 \text{ mAdc}, I_B = 5.0 \text{ mAdc}$
Small-Signal Characteristics					
Curren-Gain-Bandwidth Product	f_T	200	-	MHz	$V_{CE} = 20 \text{ Vdc}, I_C = 10 \text{ mAdc}, f = 100 \text{ MHz}$
Output Capacitance	C_{obo}	-	4.0	pF	$V_{CB} = 5.0 \text{ Vdc}, I_E = 0, f = 1.0 \text{ MHz}$
Input Capacitance	C_{ibo}	-	8.0	pF	$V_{BE} = 0.5 \text{ Vdc}, I_E = 0, f = 1.0 \text{ MHz}$
Input Impedancen	h_{ie}	1.0	10	pF	$V_{CE} = 10 \text{ Vdc}, I_C = 1.0 \text{ mAdc}, f = 1.0 \text{ kHz}$
Voltage Feedback Ratio	h_{re}	0.5	8.0	$\times 10^{-4}$	$V_{CE} = 10 \text{ Vdc}, I_C = 1.0 \text{ mAdc}, f = 1.0 \text{ kHz}$
Small-Signal Current Gain	h_{fe}	100	400	-	$V_{CE} = 10 \text{ Vdc}, I_C = 1.0 \text{ mAdc}, f = 1.0 \text{ kHz}$
Output Admittance	h_{oe}	1.0	40	θmhos	$V_{CE} = 10 \text{ Vdc}, I_C = 1.0 \text{ mAdc}, f = 1.0 \text{ kHz}$
Noise Figure	NF	-	5.0	dB	$V_{CE} = 5.0 \text{ Vdc}, I_C = 100 \mu\text{Adc}, R_S = 1.0\text{k}\Omega, f = 1.0 \text{ kHz}$
Switching Characteristics					
Delay Time	T_d	-	35	nS	$V_{CC} = 3.0 \text{ Vdc}, V_{BE} = 0.5 \text{ Vdc}, I_C = 10 \text{ mAdc}, I_{B1} = 1.0 \text{ mAdc}$
Rise Time	T_r	-	35	nS	
Storage Time	T_s	-	200	nS	$V_{CC} = 3.0 \text{ Vdc}, I_C = 10 \text{ mAdc}, I_{B1} = I_{B2} = 1.0 \text{ mAdc}$
Fall Time	T_f	-	50	nS	

3. Pulse Test : Pulse Width $\leq 300 \mu\text{s}$, Duty Cycle $\leq 2.0\%$.

CHARACTERISTIC CURVES

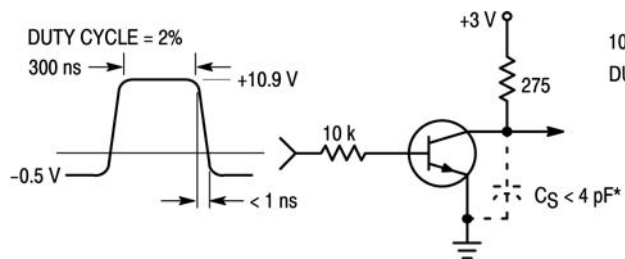


Figure 1. Delay and Rise Time Equivalent Test Circuit

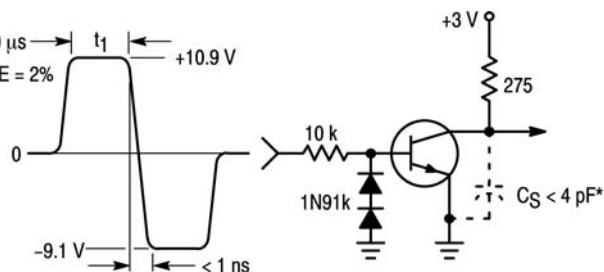


Figure 2. Storage and Fall Time Equivalent Test Circuit

* Total shunt capacitance of test jig and connectors

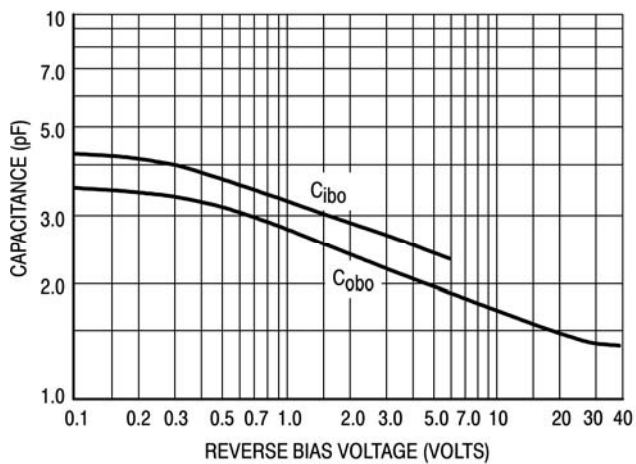


Figure 3. Capacitance

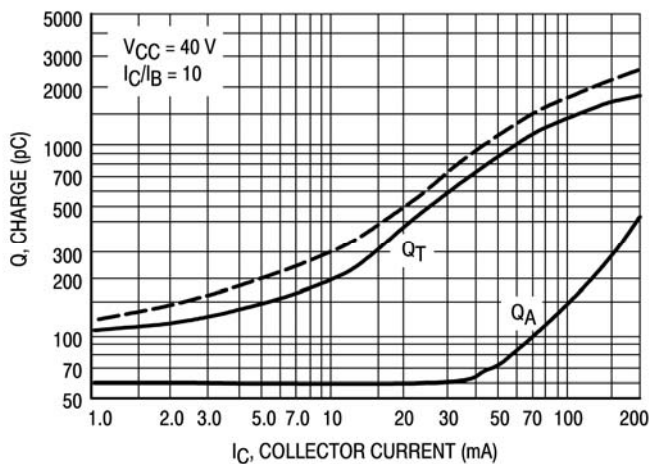


Figure 4. Charge Data

CHARACTERISTIC CURVES

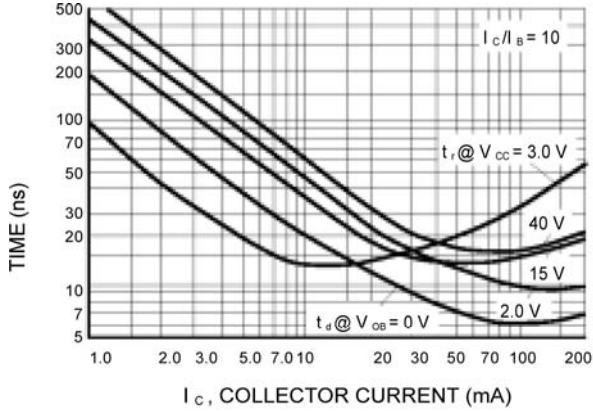


Figure 5. Turn-On Time

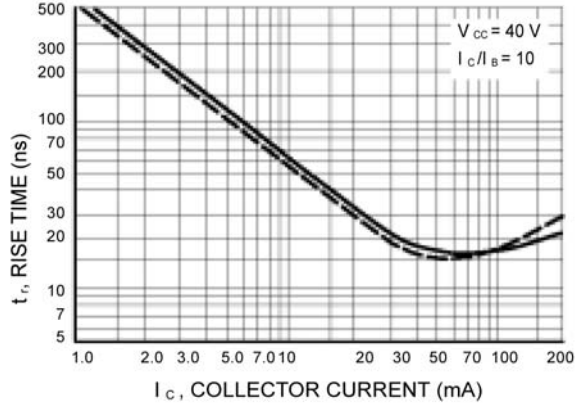


Figure 6. Rise Time

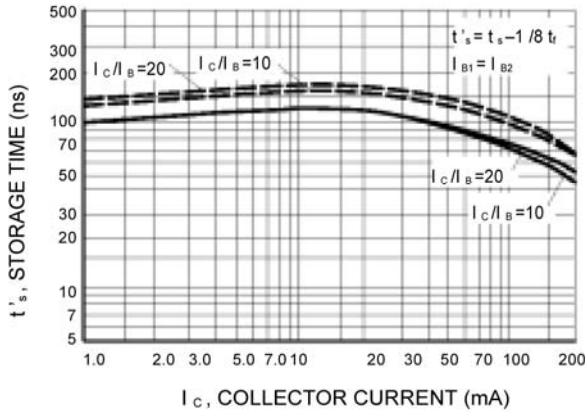


Figure 7. Storage Time

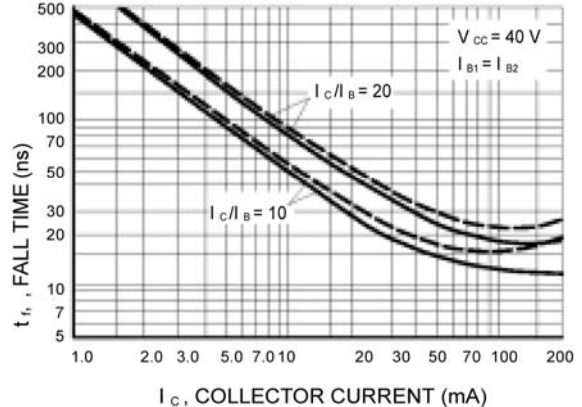


Figure 8. Fall Time

TYPICAL AUDIO SMALL-SIGNAL CHARACTERISTICS
NOISE FIGURE VARIATIONS

($V_{CE} = 5.0 \text{ Vdc}$, $T_A = 25^\circ\text{C}$, Bandwidth = 1.0 Hz)

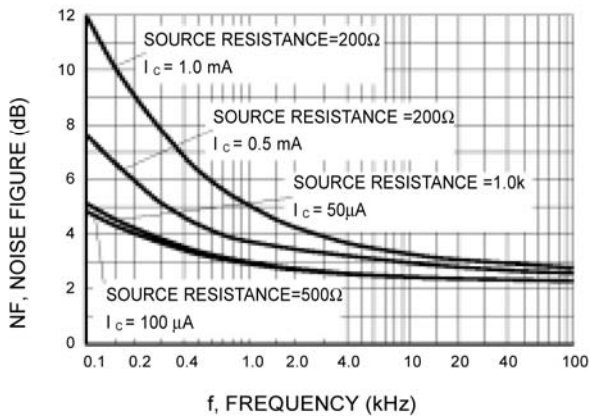


Figure 9.

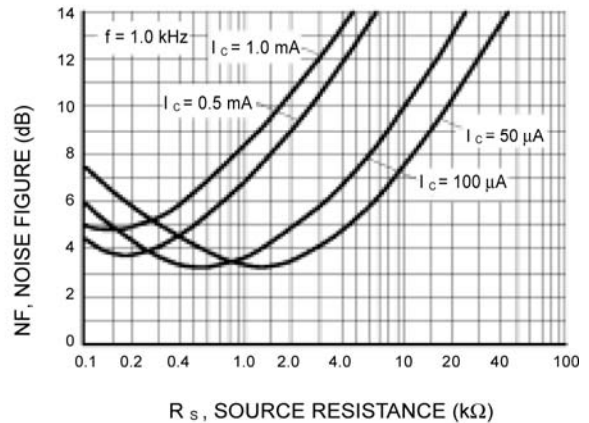


Figure 10.

CHARACTERISTIC CURVES

h PARAMETERS

($V_{CE} = 10 \text{ Vdc}$, $f = 1.0 \text{ kHz}$, $T_A = 25^\circ\text{C}$)

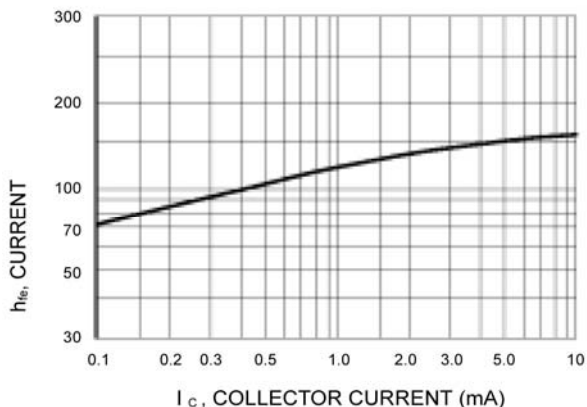


Figure 11. Current Gain

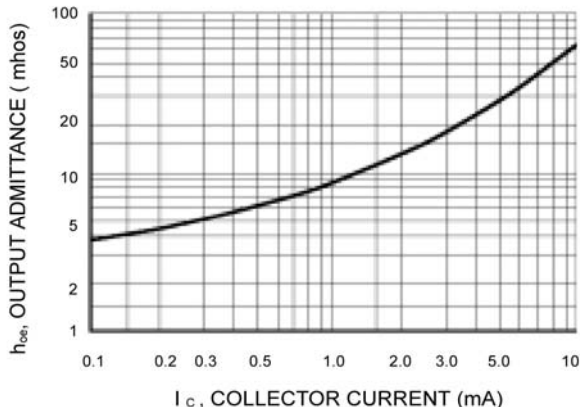


Figure 12. Output Admittance

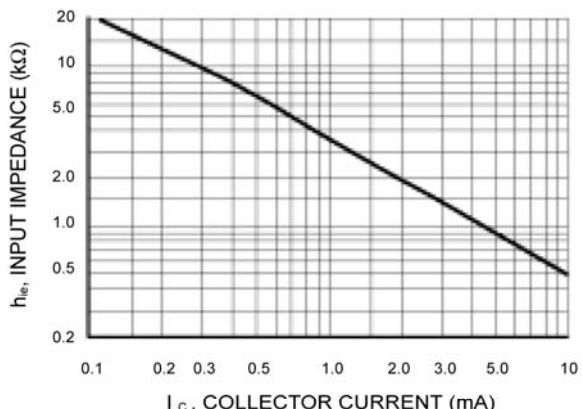


Figure 13. Input Impedance

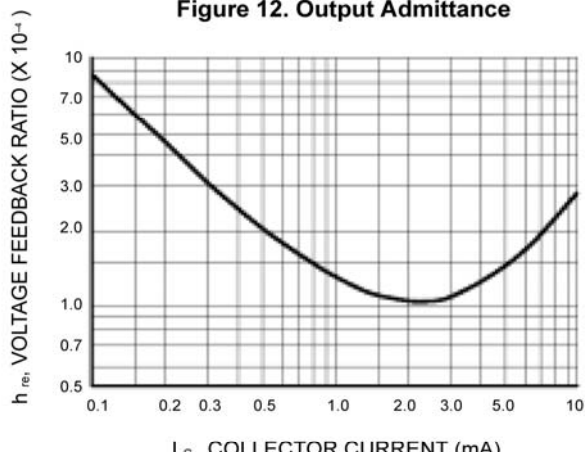


Figure 14. Voltage Feedback Ratio

TYPICAL STATIC CHARACTERISTICS

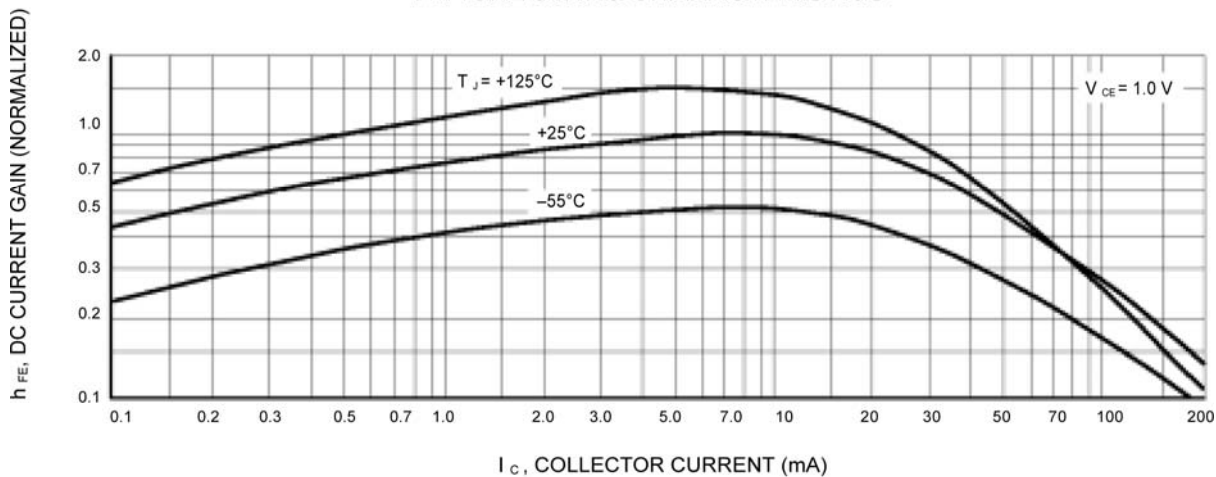


Figure 15. DC Current Gain

CHARACTERISTIC CURVES

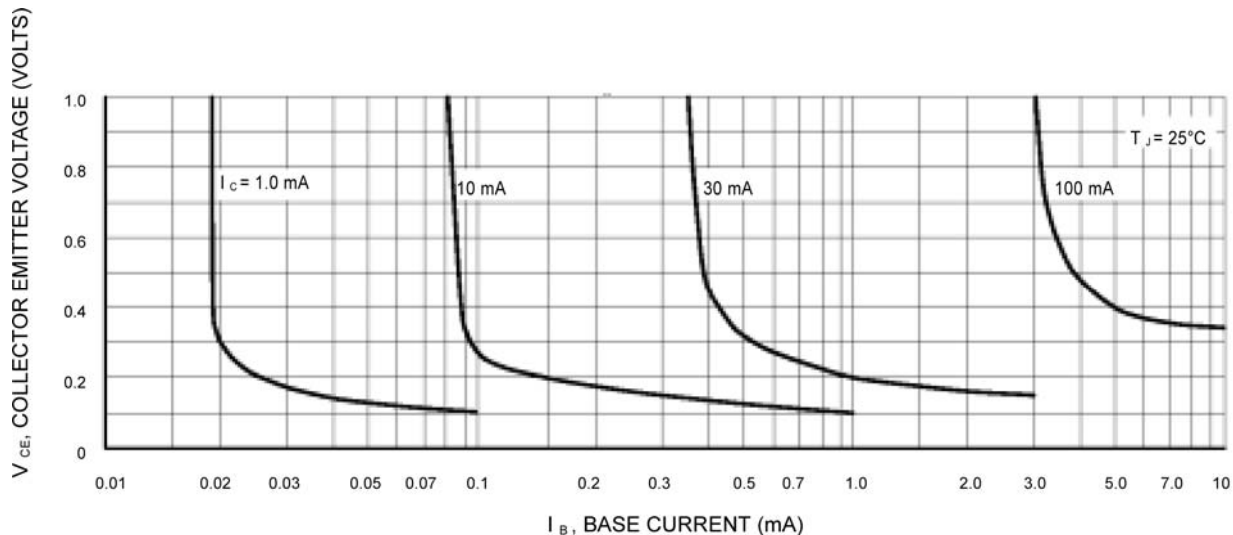


Figure 16. Collector Saturation Region

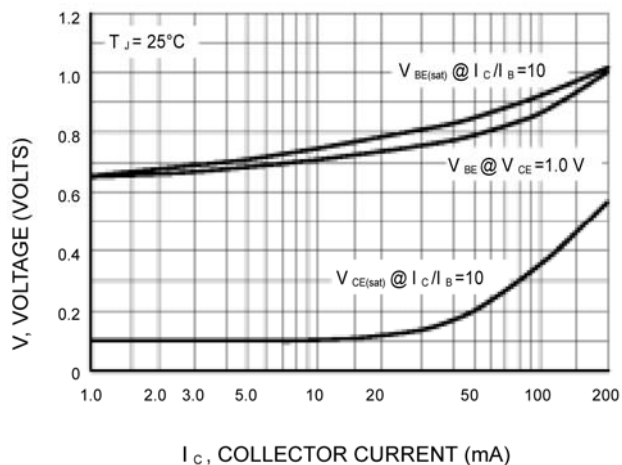


Figure 17. "ON" Voltages

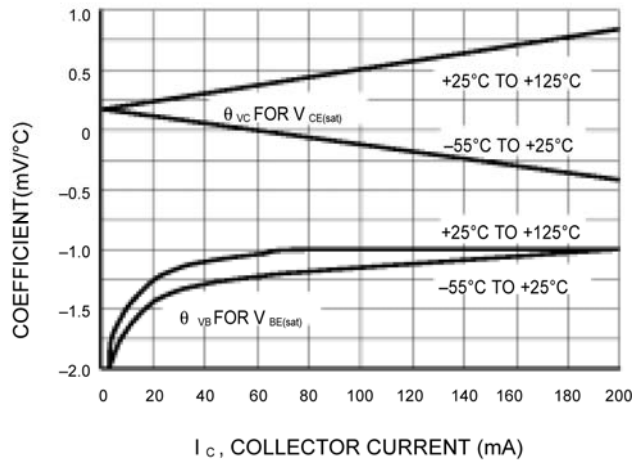


Figure 18. Temperature Coefficients